EAST Search History

Ref #	Hits	Search Query	DBs	Default Operat or	Plural s	Time Stamp
L1	0	((insualt\$3 dielectric) same (via trench recess groove hole open\$3 mesa) same (ion near5 (electrode conduct\$3)) same (indefferent near5 electrode) same (oxizdizable near5 electrode)).clm.	US-PGPU B	OR	ON	2006/02/27 14:19
L2	0	((insualt\$3 dielectric) same (via trench recess groove hole open\$3 mesa) same (ion near5 (electrode conduct\$3)) same (anode) same (cathode)).clm.	US-PGPU B	OR	ON	2006/02/27 14:19
L3	34	((insualt\$3 dielectric) same (via trench recess groove hole open\$3 mesa) same (ion near5 (electrode conduct\$3)) same electrode).clm.	US-PGPU B	OR	ON	2006/02/27 14:20
L4	3	((insualt\$3 dielectric) same (via trench recess groove hole open\$3 mesa) same (ion near5 (electrode conduct\$3)) same electrode same oxidiz\$3). clm.	US-PGPU B	OR	ON	2006/02/27 14:21

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operat or	Plural s	Time Stamp
L1	16466	(ion near5 conduct\$3)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/02/27 10:48
L2	6625	1 and electrolyte	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/02/27 10:49
L3	4103	2 and electrode	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/02/27 10:49
L4	1188	3 and oxide	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/02/27 10:49
L5	14	4 and (inuslat\$3 dielectric)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/02/27 10:50